



Properties of Silicon - Optical

Unless otherwise specified, all information is for 25°C.

Physical Properties

Symbol	Si
Atomic Number	14
Atomic Weight	28.086
Crystal Structure	diamond cubic
Density, g/cm ³	2.329
Atomic density, atoms/ cm ³	5.00 x 10 ²² (at 20°C)
Lattice Constant, nm	0.543089 (at 23°C)
Surface Tension, mN/m (=dyne/cm)	736 (liquid at melting point)
Modulus of Rupture	
MPa	125
PSI	1.8 x 10 ⁴
Mohs Hardness	7
Poisson's Ratio, 125-375K	0.279
Elastic Constants, cm ² /dyne	
S ₁₁ = 7.68 x 10 ⁻¹³	
S ₁₂ = -2.14 x 10 ⁻¹³	
S ₄₄ = 12.56 x 10 ⁻¹³	
Elastic Coefficients, dynes/cm ²	
C ₁₁ = 16.57 x 10 ¹¹	
C ₁₂ = 6.39 x 10 ¹¹	
C ₄₄ = 7.96 x 10 ¹¹	

Energy Distribution Calculations:

$$T = [(1-r)^2 e^{-at}] / [1 - r^2 e^{-2at}]$$

$$R = r + [(1-r)^2 e^{-2at}] / [1 - r^2 e^{-2at}]$$

$$A = (1-r)[1 - e^{-at}] / [1 - r e^{-at}]$$

Thermal Properties

Melting Point, °C	1412
Boiling Point, °C	2878
Heat Capacity, cal/(mole K)	
Solid	4.78
Liquid at melting point	6.755
Heat of fusion, cal/g	264
Coefficient of Linear Expansion, 10 ⁻⁶ /K	
See graph on electrical properties page	
Thermal Conductivity, W/(m K)	
See graph on electrical properties page	

Optical Properties

Index of Refraction, @ 25°C	
@ 2 microns, n =	3.456
@ 4 microns, n =	3.429
@ 6 microns, n =	3.424
Absorption Coefficient @ 25°C, cm ⁻¹	
(standard optical grade silicon, varies with resistivity)	
@ 2 microns, a =	.027
@ 4 microns, a =	.038
@ 6 microns, a =	.040
Transmission %	see graph below

T = fraction of energy transmitted

R = fraction of energy reflected

A = fraction of energy absorbed

r = reflectivity = [(n-1)/(n+1)]²

a = absorption coefficient, cm⁻¹

t = thickness, cm

OPTICAL GRADE SILICON Transmission VS. Wavelength

